## NSN 5962-01-201-7749

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-201-7749 **Body Length:** 1.485 inches **Body Width:** Between 0.590 inches and 0.625 inches **Body Height:** 0.217 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Electrostatic sensitive and programmable and ultraviolet erasable and monolithic **Inclosure Material:** Ceramic or glass or metal **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 17 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.6 volts power source and 6.5 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 14933-82025 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a **Unit Of Measure:** 

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**Demilitarization:** Yes - demil/mli